# High Performance Low-Power, LDO Regulator with Enable

The NCP600 provides 150 mA of output current at fixed voltage options, or an adjustable output voltage from 5.0 V down to 1.25 V. It is designed for portable battery powered applications and offers high performance features such as low power operation, fast enable response time, and low dropout.

The device is designed to be used with low cost ceramic capacitors and is packaged in the TSOP-5 and DFN6, 2x2.2 packages.

#### **Features**

- Output Voltage Options:
   Adjustable, 1.3 V, 1.5 V, 1.8 V, 2.5 V, 2.8 V, 3.0 V, 3.3 V, 3.5 V, 5.0 V
- Ultra-Low Dropout Voltage of 150 mV at 150 mA
- Adjustable Output by External Resistors from 5.0 V down to 1.25 V
- Fast Enable Turn-on Time of 15 μs
- Wide Supply Voltage Range Operating Range
- Excellent Line and Load Regulation
- High Accuracy up to 1.5% Output Voltage Tolerance over All Operating Conditions
- Typical Noise Voltage of 50 μV<sub>rms</sub> without a Bypass Capacitor
- Pb-Free Package is Available

#### **Typical Applications**

- SMPS Post-Regulation
- Hand-held Instrumentation
- Noise Sensitive Circuits VCO, RF Stages, etc.
- Camcorders and Cameras

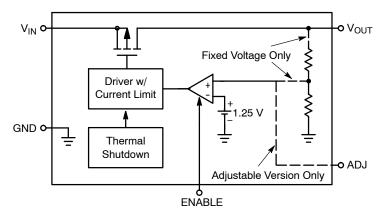


Figure 1. Simplified Block Diagram



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### MARKING DIAGRAMS



TSOP-5 SN SUFFIX CASE 483





6 PIN DFN, 2x2.2 MN SUFFIX CASE 506BA



XX = Specific Device Codexxx = Specific Device Code

M = Date Code

A = Assembly Location Y = Year

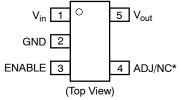
= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 13 of this data sheet.

#### **PIN CONNECTIONS**



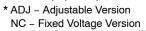


Figure 2. Pin Connections - TSOP5

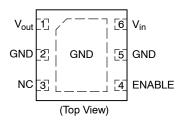


Figure 3. Pin Connections - DFN6

#### PIN FUNCTION DESCRIPTION

Pin No.			
DFN6	DFN6 TSOP-5		Description
3	4	ADJ/NC	Output Voltage Adjust Input (Adjustable Version), No Connection (Fixed Voltage Versions) (Note 1)
2, 5, EPAD	2	GND	Power Supply Ground; Device Substrate
4	3	ENABLE	The Enable Input places the device into low–power standby when pulled to logic low (< 0.4 V). Connect to $V_{in}$ if the function is not used.
6	1	V <sub>in</sub>	Positive Power Supply Input
1	5	V <sub>out</sub>	Regulated Output Voltage

<sup>1.</sup> True no connect. Printed circuit board traces are allowable.

#### **ABSOLUTE MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Input Voltage Range (Note 2)	V <sub>in</sub>	-0.3 to 6.5	V
Output, Enable, Adjustable Voltage Range	V <sub>out</sub> , ENABLE, ADJ	-0.3 to 6.5 (or V <sub>in</sub> + 0.3) Whichever is Lower	V
Maximum Junction Temperature	T <sub>J(max)</sub>	150	°C
Storage Temperature Range	T <sub>STG</sub>	-65 to 150	°C
ESD Capability, Human Body Model (Note 3)	ESD <sub>HBM</sub>	3500	V
ESD Capability, Machine Model (Note 3)	ESD <sub>MM</sub>	200	V
Moisture Sensitivity Level	MSL	MSL1/260	-

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 2. Refer to ELÉCTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
- 3. This device series incorporates ESD protection and is tested by the following methods:
  - ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)
  - ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)
  - Latchup Current Maximum Rating: ≤150 mA per JEDEC standard: JESD78.

#### THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, DFN6, 2x2.2 mm (Note 4) Thermal Resistance, Junction-to-Air (Note 5)	$R_{ hetaJA}$	122	°C/W
Thermal Characteristics, TSOP-5 (Note 4) Thermal Resistance, Junction-to-Air (Note 5)	$R_{ hetaJA}$	215	°C/W

- 4. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
- 5. Values based on copper area of 645 mm<sup>2</sup>, 1 oz copper thickness.

#### **OPERATING RANGES** (Note 6)

Rating	Symbol	Min	Max	Unit
Operating Input Voltage (Note 7)	V <sub>in</sub>	1.75 V	6	V
Adjustable Output Voltage (Adjustable Version Only)	V <sub>out</sub>	1.25	5.0	V
Output Current	l <sub>out</sub>	0	150	mA
Ambient Temperature	T <sub>A</sub>	-40	125	°C

- 6. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
- 7. Minimum  $V_{in}$  = 1.75 V or  $(V_{out} + V_{DO})$ , whichever is higher.

**ELECTRICAL CHARACTERISTICS** ( $V_{in}$  = 1.750 V,  $V_{out}$  = 1.250 V,  $C_{in}$  =  $C_{out}$  =1.0  $\mu$ F, for typical values  $T_A$  = 25°C, for min/max values  $T_A$  = -40°C to 125°C, unless otherwise specified.) (Note 8)

Characteristic Syr		Test Conditions	Min	Тур	Max	Unit
Regulator Output (Adjustable Voltage Version)						•
Output Voltage	V <sub>out</sub>	I <sub>out</sub> = 1.0 mA to 150 mA V <sub>in</sub> = 1.75 V to 6.0 V, V <sub>out</sub> = ADJ	1.231 (-1.5%)	1.250	1.269 (+1.5%)	V
Power Supply Ripple Rejection $(V_{in} = V_{out} + 1.0 \text{ V} + 0.5 \text{ V}_{p-p})$	PSRR	I <sub>out</sub> = 1.0 mA to 150 mA f = 120 Hz f = 1.0 kHz f = 10 kHz	- - -	62 55 38	- - -	dB
Line Regulation	Reg <sub>line</sub>	V <sub>in</sub> = 1.750 V to 6.0 V, I <sub>out</sub> = 1.0 mA	-	1.0	10	mV
Load Regulation	Reg <sub>load</sub>	I <sub>out</sub> = 1.0 mA to 150 mA	-	2.0	15	mV
Output Noise Voltage (Note 9)	Vn	f = 10 Hz to 100 kHz	-	50	_	$\mu V_{rms}$
Output Short Circuit Current	I <sub>sc</sub>	V <sub>out</sub> = 0 V	300	550	800	mA
Dropout Voltage 1.25 V 1.3 V 1.5 V 1.8 V 2.5 V 2.8 V to 5.0 V	V <sub>DO</sub>	Measured at: V <sub>out</sub> – 2.0%, I <sub>out</sub> = 150 mA	- - - - -	175 175 150 125 100 75	250 250 225 175 150 125	mV

Regulator Output (Fixed Voltage Version) ( $V_{in} = V_{out} + 0.5 \text{ V}$ ,  $C_{in} = C_{out} = 1.0 \mu\text{F}$ , for typical values  $T_A = 25^{\circ}\text{C}$ , for min/max values  $T_A = -40^{\circ}\text{C}$  to 125°C; unless otherwise noted.) (Notes 8)

Output Voltage 1.3 V 1.5 V 1.8 V 2.5 V 2.8 V 3.0 V 3.3 V 3.5 V 5.0 V	Vout	l <sub>out</sub> = 1.0 mA to 150 mA V <sub>in</sub> = (V <sub>out</sub> + 0.5 V) to 6.0 V	1.274 1.470 1.764 2.450 2.744 2.940 3.234 3.430 4.900 (-2%)		1.326 1.530 1.836 2.550 2.856 3.060 3.366 3.570 5.100 (+2%)	V
Power Supply Ripple Rejection (Note 9) (V <sub>in</sub> = V <sub>out</sub> + 1.0 V + 0.5 V <sub>p-p</sub> )	PSRR	I <sub>out</sub> = 1.0 mA to 150 mA f = 120 Hz f = 1.0 kHz f = 10 kHz	- - -	62 55 38	- - -	dB
Line Regulation	Reg <sub>line</sub>	V <sub>in</sub> = 1.750 V to 6.0 V, I <sub>out</sub> = 1.0 mA	-	1.0	10	mV
Load Regulation 1.3 V to 1.5 V 1.8 V 2.5 V to 5.0 V	Reg <sub>load</sub>	I <sub>out</sub> = 1.0 mA to 150 mA	- - -	2.0 2.0 2.0	20 25 30	mV
Output Noise Voltage (Note 9)	V <sub>n</sub>	f = 10 Hz to 100 kHz	-	50	-	$\mu V_{rms}$
Output Short Circuit Current	I <sub>sc</sub>	V <sub>out</sub> = 0 V	300	550	800	mA
Dropout Voltage 1.3 V 1.5 V 1.8 V 2.5 V 2.8 V to 5.0 V	V <sub>DO</sub>	Measured at: V <sub>out</sub> – 2.0%	- - - -	175 150 125 85 75	250 225 175 175 125	mV

<sup>8.</sup> Performance guaranteed over the indicated operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

9. Values based on design and/or characterization.

**ELECTRICAL CHARACTERISTICS** ( $V_{in} = V_{out} + 0.5 \text{ V}$ , For Typical Values  $T_A = 25^{\circ}\text{C}$ , For Min/Max Values  $T_A = -40^{\circ}\text{C}$  to 125°C, unless otherwise specified.) (Note 10)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
General						
Disable Current	I <sub>DIS</sub>	ENABLE = 0 V, $V_{in}$ = 6 V $T_A$ = -40°C to 85°C	-	0.01	1.0	μΑ
Ground Current 1.25 V (Adjustable) 1.3 V 1.5 V 1.8 V to 3.0 V 3.3 V to 5.0 V	I <sub>GND</sub>	ENABLE = 0.9 V, I <sub>out</sub> = 1.0 mA to 150 mA	- - - -	100 135 135 140 145	135 150 170 175 180	μΑ
Thermal Shutdown Temperature (Note 11)	T <sub>SD</sub>		-	175	-	°C
Thermal Shutdown Hysteresis (Note 11)	T <sub>SH</sub>		-	10	-	°C
ADJ Input Bias Current	I <sub>ADJ</sub>		-0.75	-	0.75	μΑ
Chip Enable						
ENABLE Input Threshold Voltage	V <sub>th(EN)</sub>					V
Voltage Increasing, Logic High			0.9	_	-	
Voltage Decreasing, Logic Low			_	_	0.4	
Enable Input Bias Current (Note 11)	I <sub>EN</sub>		-	3.0	100	nA
Timing	•	•	•	•	•	•
Output Turn On Time (Note 11) 1.25 V 1.3 V to 3.5 V 5.0 V	t <sub>EN</sub>	ENABLE = 0 V to V <sub>in</sub>	- - -	15 15 30	25 25 50	μs

<sup>10.</sup> Performance guaranteed over the indicated operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 11. Values based on design and/or characterization.

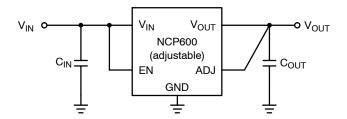


Figure 4. Typical Application Circuit for V<sub>out</sub> = 1.25 V (Adjustable Version)

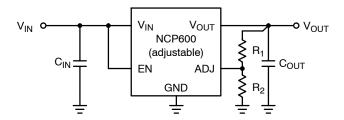


Figure 5. Typical Application Circuit for Adjustable V<sub>out</sub>

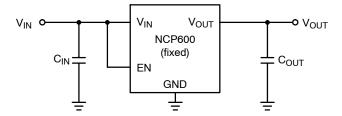
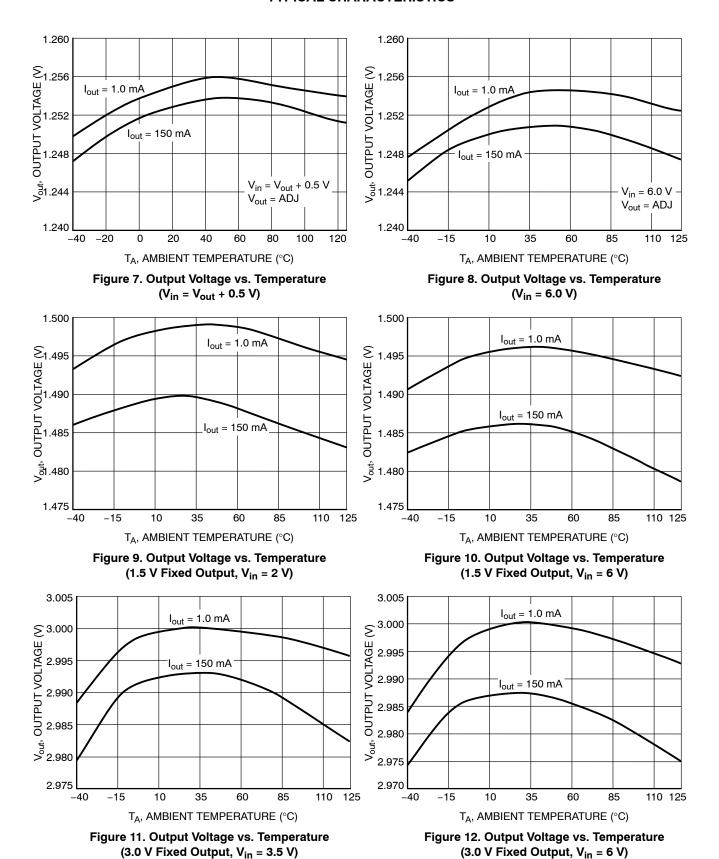
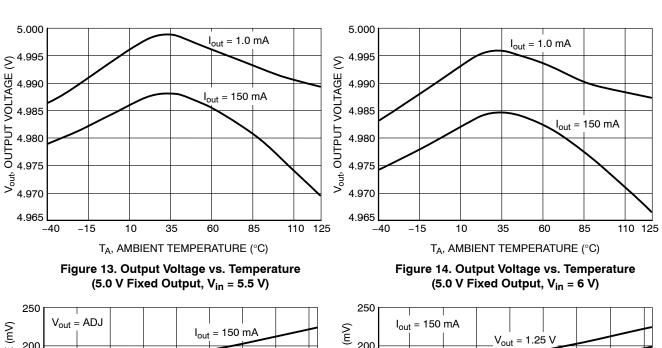


Figure 6. Typical Application Circuit (Fixed Voltage Version)





V<sub>DO</sub>, DROPOUT VOLTAGE (mV) 200 150 100  $I_{out} = 50 \text{ mA}$ 50  $I_{out} = 1.0 \text{ mA}$ -20 20 40 60 80 100 -40 0 120 TA, AMBIENT TEMPERATURE (°C)

Figure 15. Dropout Voltage vs. Temperature (Over Current Range)

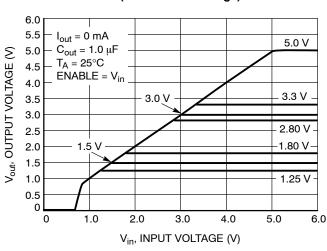


Figure 17. Output Voltage vs. Input Voltage

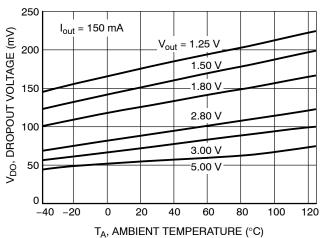


Figure 16. Dropout Voltage vs. Temperature (Over Output Voltage)

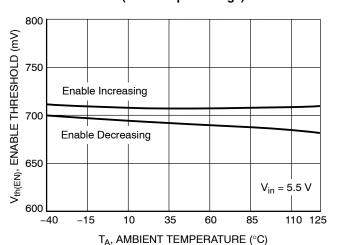


Figure 18. Enable Threshold vs. Temperature

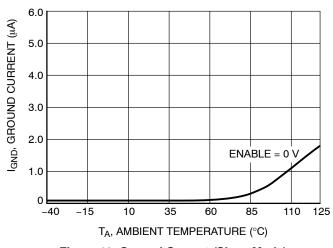


Figure 19. Ground Current (Sleep Mode) vs.
Temperature

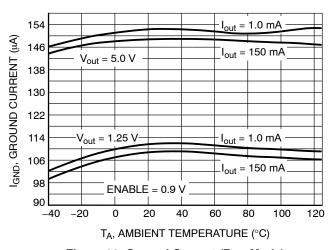


Figure 20. Ground Current (Run Mode) vs.
Temperature

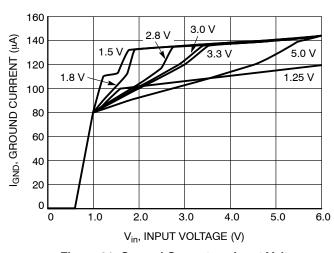


Figure 21. Ground Current vs. Input Voltage

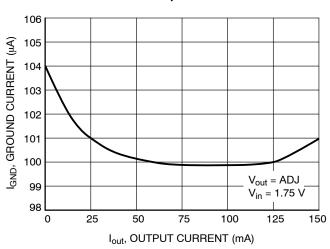


Figure 22. Ground Current vs. Output Current

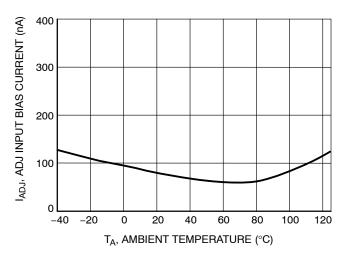
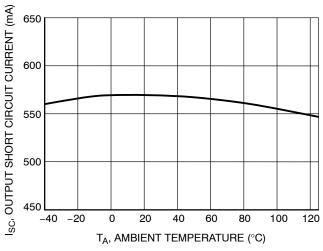


Figure 23. ADJ Input Bias Current vs. Temperature

#### **TYPICAL CHARACTERISTICS**

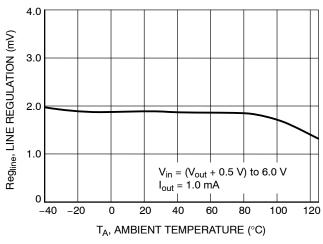
700



600 ILIM, CURRENT LIMIT (mA) 500 400 300 200 100 0 0 1.0 2.0 6.0 3.0 4.0 5.0 V<sub>in</sub>, INPUT VOLTAGE (V)

Figure 24. Output Short Circuit Current vs.
Temperature

Figure 25. Current Limit vs. Input Voltage



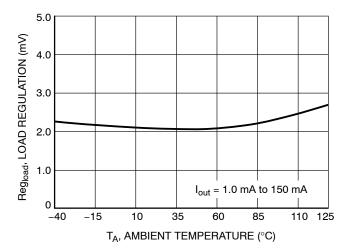
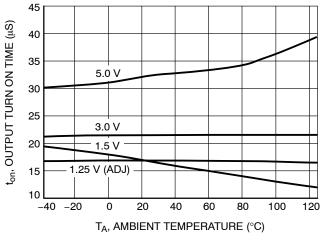


Figure 26. Line Regulation vs. Temperature

Figure 27. Load Regulation vs. Temperature



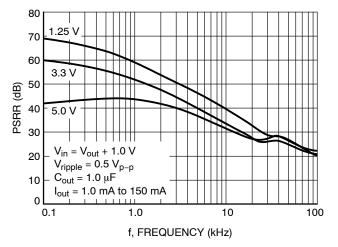


Figure 28. Output Turn On Time vs. Temperature

Figure 29. Power Supply Ripple Rejection vs. Frequency

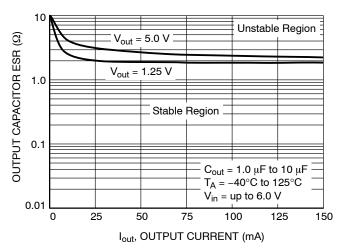


Figure 30. Output Stability with Output Capacitor ESR over Output Current

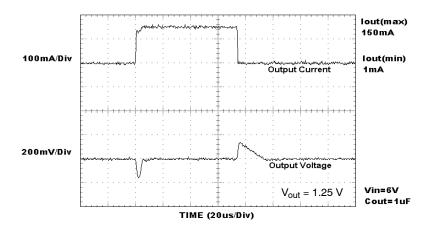


Figure 31. Load Transient Response (1.0 μF)

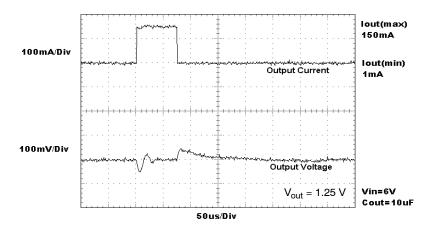


Figure 32. Load Transient Response (10  $\mu$ F)

#### **DEFINITIONS**

#### **Load Regulation**

The change in output voltage for a change in output load current at a constant temperature.

#### **Dropout Voltage**

The input/output differential at which the regulator output no longer maintains regulation against further reductions in input voltage. Measured when the output drops 2% below its nominal. The junction temperature, load current, and minimum input supply requirements affect the dropout level.

#### **Output Noise Voltage**

This is the integrated value of the output noise over a specified frequency range. Input voltage and output load current are kept constant during the measurement. Results are expressed in  $\mu V_{rms}$  or  $nV/\sqrt{Hz}$ .

#### **Disable and Ground Current**

Ground Current ( $I_{\rm GND}$ ) is the current that flows through the ground pin when the regulator operates with a load on its output. This consists of internal IC operation, bias, etc. It is actually the difference between the input current (measured through the LDO input pin) and the output load current. If the regulator has an input pin that reduces its internal bias and shuts off the output (enable/disable function), this term is called the disable current ( $I_{\rm DIS}$ ).

#### Line Regulation

The change in output voltage for a change in input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that the average junction temperature is not significantly affected.

#### **Line Transient Response**

Typical output voltage overshoot and undershoot response when the input voltage is excited with a given slope.

#### **Load Transient Response**

Typical output voltage overshoot and undershoot response when the output current is excited with a given slope between no-load and full-load conditions.

#### **Thermal Protection**

Internal thermal shutdown circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated at typically 175°C, the regulator turns off. This feature is provided to prevent failures from accidental overheating.

#### **Maximum Package Power Dissipation**

The power dissipation level at which the junction temperature reaches its maximum operating value.

#### **APPLICATIONS INFORMATION**

The NCP600 series regulator is self-protected with internal thermal shutdown and internal current limit. Typical application circuits are shown in Figures 4 and 5.

### Input Decoupling (Cin)

A ceramic or tantalum 1.0  $\mu F$  capacitor is recommended and should be connected close to the NCP600 package. Higher capacitance and lower ESR will improve the overall line transient response.

### Output Decoupling (Cout)

The NCP600 is a stable component and does not require a minimum Equivalent Series Resistance (ESR) for the output capacitor. The minimum output decoupling value is  $1.0~\mu F$  and can be augmented to fulfill stringent load transient requirements. The regulator works with ceramic chip capacitors as well as tantalum devices. Larger values improve noise rejection and load regulation transient response. Figure 30 shows the stability region for a range of operating conditions and ESR values.

#### No-Load Regulation Considerations

The NCP600 adjustable regulator will operate properly under conditions where the only load current is through the resistor divider that sets the output voltage. However, in the case where the NCP600 is configured to provide a 1.250 V

output, there is no resistor divider. If the part is enabled under no-load conditions, leakage current through the pass transistor at junction temperatures above 85°C can approach several microamps, especially as junction temperature approaches 150°C. If this leakage current is not directed into a load, the output voltage will rise up to a level approximately 20 mV above nominal.

The NCP600 contains an overshoot clamp circuit to improve transient response during a load current step release. When output voltage exceeds the nominal by approximately 20 mV, this circuit becomes active and clamps the output from further voltage increase. Tying the ENABLE pin to  $V_{in}$  will ensure that the part is active whenever the supply voltage is present, thus guaranteeing that the clamp circuit is active whenever leakage current is present.

When the NCP600 adjustable regulator is disabled, the overshoot clamp circuit becomes inactive and the pass transistor leakage will charge any capacitance on  $V_{out}$ . If no load is present, the output can charge up to within a few millivolts of  $V_{in}$ . In most applications, the load will present some impedance to  $V_{out}$  such that the output voltage will be inherently clamped at a safe level. A minimum load of  $10~\mu A$  is recommended.

#### **Noise Decoupling**

The NCP600 is a low noise regulator and needs no external noise reduction capacitor. Unlike other low noise regulators which require an external capacitor and have slow startup times, the NCP600 operates without a noise reduction capacitor, has a typical 15 µs start up delay and achieves a 50 µV<sub>rms</sub> overall noise level between 10 Hz and 100 kHz.

#### **Enable Operation**

The enable pin will turn the regulator on or off. The threshold limits are covered in the electrical characteristics table in this data sheet. The turn-on/turn-off transient voltage being supplied to the enable pin should exceed a slew rate of 10 mV/us to ensure correct operation. If the enable function is not to be used then the pin should be connected to V<sub>in</sub>.

#### **Output Voltage Adjust**

The output voltage can be adjusted from 1 times (Figure 4) to 4 times (Figure 5) the typical 1.250 V regulation voltage via the use of resistors between the output and the ADJ input. The output voltage and resistors are chosen using Equation 1 and Equation 2.

$$V_{out} = 1.250 \left( 1 + \frac{R_1}{R_2} \right) + \left( I_{ADJ} \times R_1 \right)$$
 (eq. 1)

$$R_2 \cong \frac{R_1}{\frac{V_{out}}{1.25} - 1}$$
 (eq. 2)

Input bias current I<sub>ADJ</sub> is typically less than 150 nA. Choose R2 arbitrarily to minimize errors due to the bias current and to minimize noise contribution to the output voltage. Use Equation 2 to find the required value for R1.

#### **Thermal**

As power in the NCP600 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part. When the NCP600 has good thermal conductivity through the PCB, the junction temperature will be relatively low with high power applications. The maximum dissipation the NCP600 can handle is given by:

$$P_{D(MAX)} = \frac{T_{J(MAX)} - T_{A}}{R_{\theta JA}}$$
 (eq. 3)

Since T<sub>J</sub> is not recommended to exceed 125°C (T<sub>J(MAX)</sub>), then the NCP600 in a DFN6 package can dissipate up to 870 mW when the ambient temperature (T<sub>A</sub>) is 25°C, and PCB area is 640 mm<sup>2</sup> and larger, see Figure 33.

The power dissipated by the NCP600 can be calculated from the following equations:

$$P_D \approx V_{in}(I_{GND} @ I_{out}) + I_{out}(V_{in} - V_{out})$$
 (eq. 4)

or

$$V_{in(MAX)} \approx \frac{P_{D(MAX)} + (V_{out} \times I_{out})}{I_{out} + I_{GND}}$$
 (eq. 5)

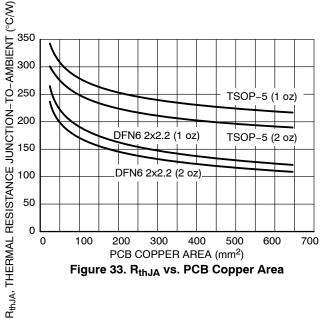


Figure 33. R<sub>thJA</sub> vs. PCB Copper Area

#### Hints

Vin and GND printed circuit board traces should be as wide as possible. When the impedance of these traces is high, there is a chance to pick up noise or cause the regulator to malfunction. Place external components, especially the output capacitor, as close as possible to the NCP600, and make traces as short as possible.

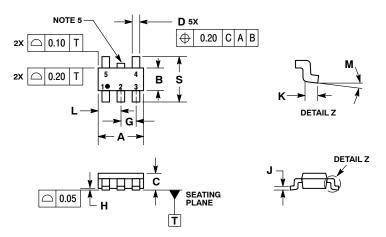
# **DEVICE ORDERING INFORMATION**

Device	Marking Code	Version	Package	Shipping*	
NCP600SNADJT1G	LIO	ADJ			
NCP600SN130T1G	LJZ	1.3 V	7		
NCP600SN150T1G	LID	1.5 V			
NCP600SN180T1G	LIE	1.8 V			
NCP600SN250T1G	ACM	2.5 V	TSOP-5	0000 /Taba & David	
NCP600SN280T1G	LIH	2.8 V	(Pb-Free)	3000 / Tape & Reel	
NCP600SN300T1G	LIJ	3.0 V			
NCP600SN330T1G	LIK	3.3 V			
NCP600SN350T1G	LJR	3.5 V			
NCP600SN500T1G	LIN	5.0 V			
NCP600MN130R2G	L2	1.3 V	DFN6 (Pb-Free)	3000 / Tape & Reel	

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **PACKAGE DIMENSIONS**

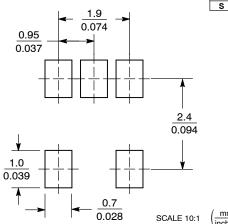
### TSOP-5 CASE 483-02 **ISSUE H**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BACE MATERIAL
  - I HILKNESS IS I HE MINIMUM THICKNESS OF BASE MATERIAL. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.
- OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

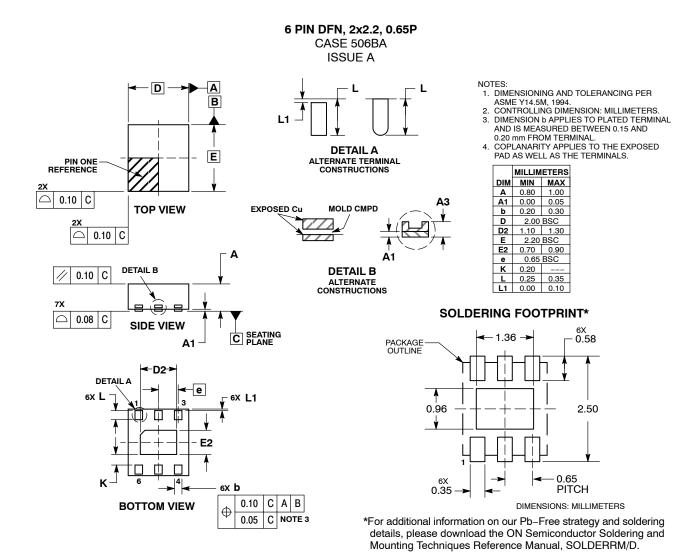
	MILLIMETERS			
DIM	MIN	MAX		
Α	3.00	BSC		
В	1.50	BSC		
ပ	0.90	1.10		
D	0.25	0.50		
G	0.95	0.95 BSC		
Н	0.01	0.10		
7	0.10	0.26		
K	0.20	0.60		
L	1.25	1.55		
М	0 °	10°		
S	2.50	3.00		

### **SOLDERING FOOTPRINT\***



<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS



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